

Supporting Information

**Kinetics enhanced hierarchical $\text{Ni}_2\text{P}_{1-x}\text{S}_x/\text{Ni}$ @carbon/graphene yolk-shell microspheres
boosting advanced sodium/potassium storage**

Experimental Section

Uniform Ni-MOFs precursor spheres synthesis. All the chemicals were directly used after purchase without further purification. The hydrothermal method was followed to synthesize Ni-MOFs precursors.¹ Under vigorous magnetic stirring, a mixture of 0.605 g $\text{Ni}(\text{NO}_3)_2 \cdot 6\text{H}_2\text{O}$, 0.21 g trimesic acid, and 2.1 g of PVP-K30 ($M_w = 40000$) was dissolved in 42 mL mixture of DMF, ethanol, and water (1:1:1, v/v/v). Then the mixture was sealed in 70 mL Teflon-lined autoclave and heated to 150 °C for 10 h. Afterward, the green precipitate was washed by DMF and ethanol for several times and dried in a vacuum oven at 60 °C for 12 h.

Yolk-shell (YS) $\text{Ni}_2\text{P}_{1-x}\text{S}_x/\text{Ni}@C/G$ spheres synthesis. The YS $\text{Ni}_2\text{P}_{1-x}\text{S}_x/\text{Ni}@C/G$ spheres were obtained via a one-step process. Briefly, 50 mg Ni-MOFs precursor spheres, and the mixture of red P and S powder were separately placed in two quartz boats, and the mixture of red P and S powder was placed at the upstream zone in a tube furnace. The varied mass ratio of P and S (2:1, 1:1, and 1:2) was first mixed with 80 mg of powder using mortar and pestle to synthesize samples with different S/P ratios. Then, the furnace was set to increase up to 450 °C for 2 h with a ramp rate of 1 °C min^{-1} bypassing Ar atmosphere to obtain YS $\text{Ni}_2\text{P}_{1-x}\text{S}_x/\text{Ni}@C/G$ microspheres. For comparison, the pure S powder and P powder replace the mixture of red P and S powder under the same above condition, respectively, were denoted as $\text{Ni}_9\text{S}_8/\text{Ni}@C/G$, and $\text{Ni}_2\text{P}/\text{Ni}@C/G$ composites, respectively. Moreover, the Ni-MOF precursor was calcined in air at 420 °C for 3h with 1 °C min^{-1} , and the porous NiO was obtained. Then, 50 mg porous NiO was phosphated by 750 mg $\text{NaH}_2\text{PO}_2 \cdot \text{H}_2\text{O}$ at 350 °C for 2h to synthesize Ni_2P , and sulfided by 100 mg S powder at 450 °C for 2h and then 600 °C 1h to prepare $\text{Ni}_9\text{S}_8/\text{NiS}$ in Ar atmosphere, respectively.

Materials Characterization. X-ray diffraction (Bruker D8 ADVANCE) with Cu $K\alpha$ radiation was employed to identify the composition and phase structure of the as-prepared Ni-based hybrids. Field emission scanning electron microscopy SEM (FESEM, SU8220, 20 kV) operating at 5 kV was used to characterize the morphology. TEM, HAADF-STEM, and elemental mapping images were recorded on an FEI Tecnai F20 transmission electron microscope. The valence state of the samples was investigated by X-ray photoelectron spectroscopy (XPS, Axis Ultra DLD, Kratos), using a monochromatic Al- $K\alpha$ as radiation exciting source. N_2 adsorption/desorption isotherm was investigated at 77K with an automated gas sorption analyzer

(Micromeritics ASAP 2460). The carbon and power contents in the hybrids were determined by thermogravimetric analysis (TGA, TGA/DSC 3+, Switzerland) under Ar and air atmosphere with a heating rate of 10 °C min⁻¹, respectively.

Fabrication of half-cell and full-cell. The electrochemical performances of as-prepared YS Ni-based composites were performed via CR2025 coin-type cells. For fabrication of the working electrodes, the slurry of working electrodes consisted of 70 wt % active materials of the YS Ni-based composites, 20 wt % acetylene black, and 10 wt % polyvinylidene fluoride in methyl-2-pyrrolidone, which were mixed, then coated on Cu foil and dried at 80 °C under vacuum for 12 h. The mass loading of each working electrode was ~ 1.0 - 1.1 mg cm⁻². For sodium-ion batteries (SIBs) half-cell, sodium foil was the counter electrode, and the was the 1 M NaClO₄ in ethylene carbonate (EC)/diethyl carbonate (1:1, v/v) with 5 wt % fluoroethylene carbonate was used as the electrolyte. For potassium ion batteries (PIBs) half-cell, the potassium foil was employed as the counter electrode, and the electrolyte in the cell was 1 M KPF₆ in EC/propylene carbonate (1:1 v/v). SICs full cell was also fabricated with the optimized Ni₂P_{0.75}S_{0.25}/Ni@C/G as the anode and activated carbon (AC) as the cathode in the same electrolyte, and the mass ratio of cathode/anode was 3:1. A Whatman GF/F glass microfiber filter was used as the separator for SIBs, PIBs, and SICs.

Electrochemical testing. Galvanostatic discharge/charge (GDC) test and cycle-life tests were performed on a Land 2001A tester (Wuhan Land Electronics. Ltd.). Cyclic voltammetry (CV), GDC measurements of NICs, and electrical impedance spectroscopy (EIS) test from 100 kHz to 10 mHz. The specific capacitance (C , F g⁻¹), energy density (E , Wh kg⁻¹) and power density (P , W kg⁻¹) of NICs were calculated using the following equations^{2, 3}:

$$C = I / [(dV / dt) \times m] \approx I\Delta t / m\Delta V,$$

$$E = 0.5 CV^2$$

$$P = E/t$$

where I is the discharge current, Δt is the discharge time (s), m is the total mass of active material of the two electrodes, and V stands for working voltage, respectively.

Computational Methods. The first principle calculations have been employed to calculate the Na⁺ ion adsorption energy and diffusion energy barrier of Ni₂P (111),

Ni₉S₈ (222), and layer-Ni₂P (111)-Ni₉S₈ (222) hetero-structure, respectively. The lattice mismatch was as follows: $\Delta u = -4.94\%$, $\Delta v = -3.17\%$. All calculations were based on density functional theory (DFT) and performed using the Cambridge Serial Total Energy Package (CASTEP) module, employing the ultra-soft pseudo-potential.⁴ The exchange-correlation functional under the generalized gradient approximation (GGA) level was carried out using the Perdew-Burke-Ernzerhof (PBE) for solids functional.⁵ The cut-off energy and the vacuum distance between the slabs were set to 517 eV and 20 Å, respectively. The Broyden-Fletcher-Goldfarb-Shanno scheme was employed as the minimization algorithm in the geometric optimization process until the force of each atom was smaller than 0.03 eV/Å.⁶ The Brillouin zone was set as $3 \times 3 \times 1$ *k*-grid, and the vacuum distance between the slabs was set to 20 Å.

In the computation of the Na⁺ adsorption energy, the following equation was performed:

$$E_{\text{ads}} = E_{\text{slab-substrate-Na}^+} - (E_{\text{slab-substrate}} + E_{\text{slab-Na}^+})$$

where $E_{\text{slab-substrate}}$ and $E_{\text{slab-Na}^+}$ are the total energy of the relaxed, isolated substrate slabs (Ni₂P (111), Ni₉S₈ (222), and Ni₂P(111)-Ni₉S₈(222) interface) and single Na⁺ in the same slab, respectively. $E_{\text{slab-substrate-Na}^+}$ is the total energy of the slab-substrate-Na⁺ system. The migration barrier of Na-ion was conducted using the supercell by the complete LST/QST method in the CASTEP module.

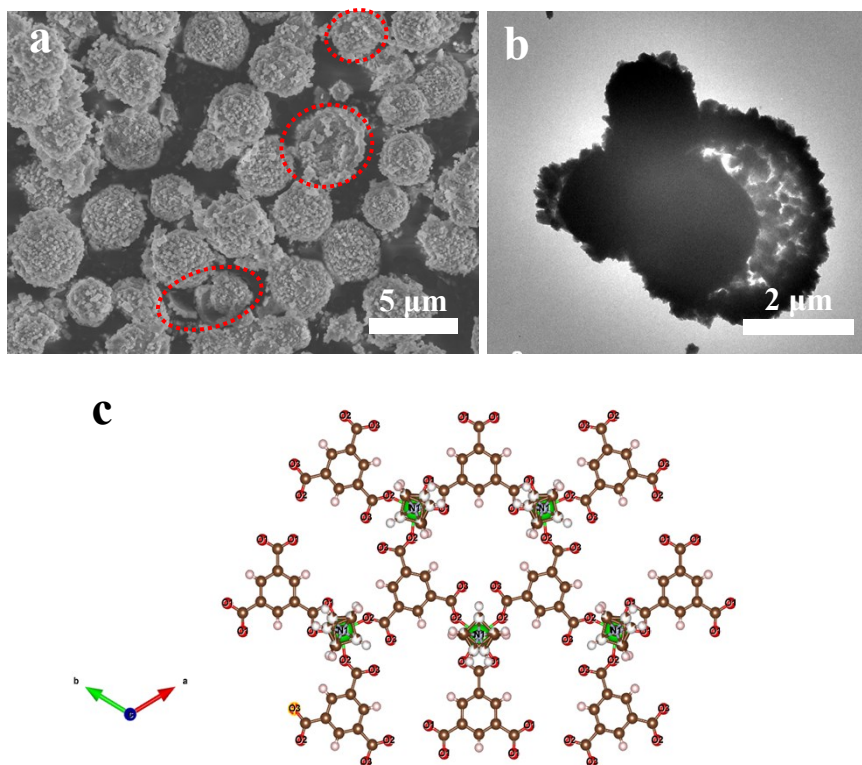


Figure S1 (a) SEM, (b) TEM image, and (c) Coordination environments of Ni²⁺ ions in the asymmetric units of Ni-MOF.

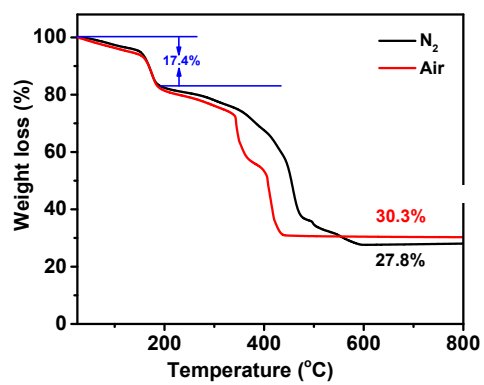


Figure S2 TGA-DSC curves of Ni-MOF in the Ar and air atmosphere.

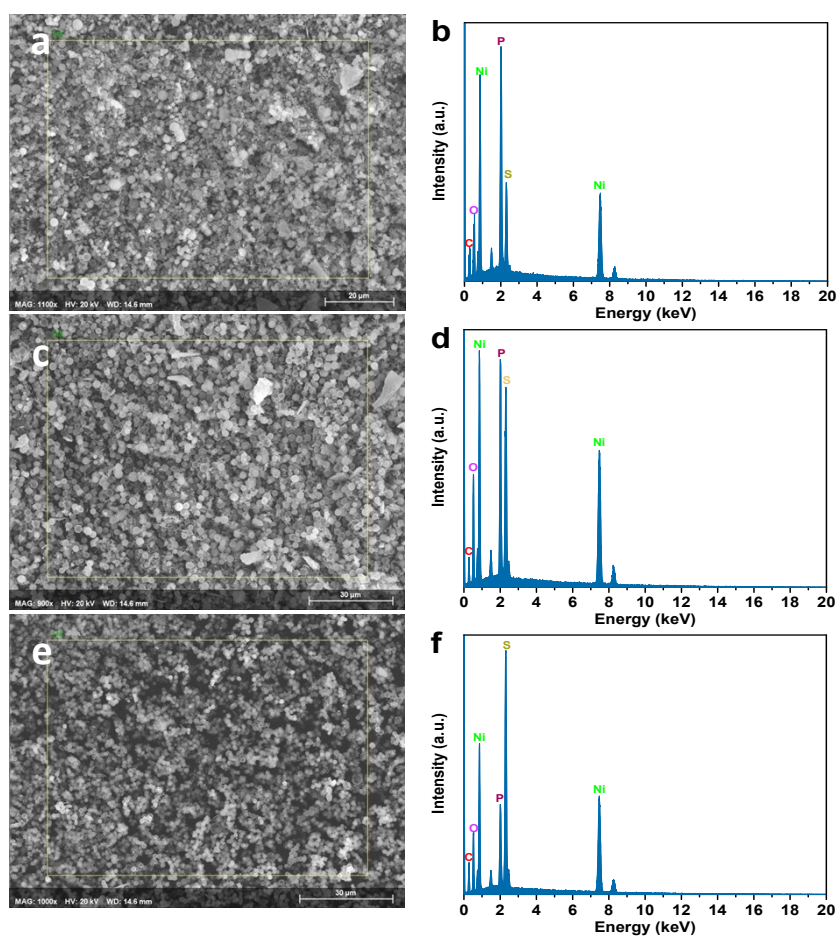


Figure S3 SEM images and EDX spectra of YS $\text{Ni}_2\text{P}_{1-x}\text{S}_x/\text{Ni}@C/\text{G}$, where (a, b), (c, d), and (e, f) correspond to $x = 0.25$, 0.42 , and 0.53 , respectively.

Table S1 The x value of the $\text{Ni}_2\text{P}_{1-x}\text{S}_x/\text{Ni}@C/\text{G}$ determined by EDX.

Sample	X value	Mass weight	
		P power (g)	S power (g)
YS $\text{Ni}_2\text{P}/\text{Ni}@C/\text{G}$	0	0.080	0
YS $\text{Ni}_2\text{P}_{0.75}\text{S}_{0.25}/\text{Ni}@C/\text{G}$	0.25	0.053	0.027
YS $\text{Ni}_2\text{P}_{0.58}\text{S}_{0.42}/\text{Ni}@C/\text{G}$	0.42	0.040	0.040
YS $\text{Ni}_2\text{P}_{0.37}\text{S}_{0.53}/\text{Ni}@C/\text{G}$	0.53	0.027	0.053
YS $\text{Ni}_9\text{S}_8/\text{Ni}@C/\text{G}$	0.89	0	0.080

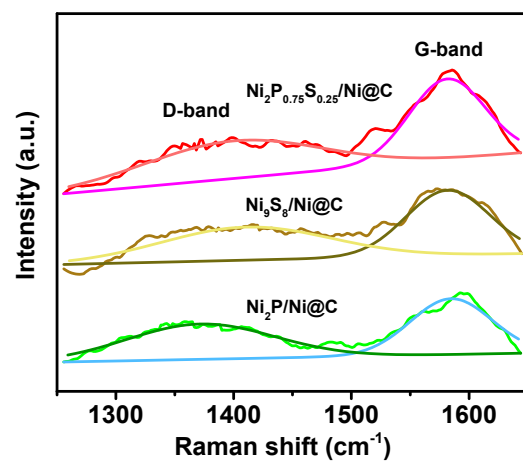


Figure S4 Raman spectra of $\text{Ni}_2\text{P}/\text{Ni@C}/\text{G}$, $\text{Ni}_9\text{S}_8/\text{Ni@C}/\text{G}$, and $\text{Ni}_2\text{P}_{0.75}\text{S}_{0.25}/\text{Ni@C}/\text{G}$, respectively.

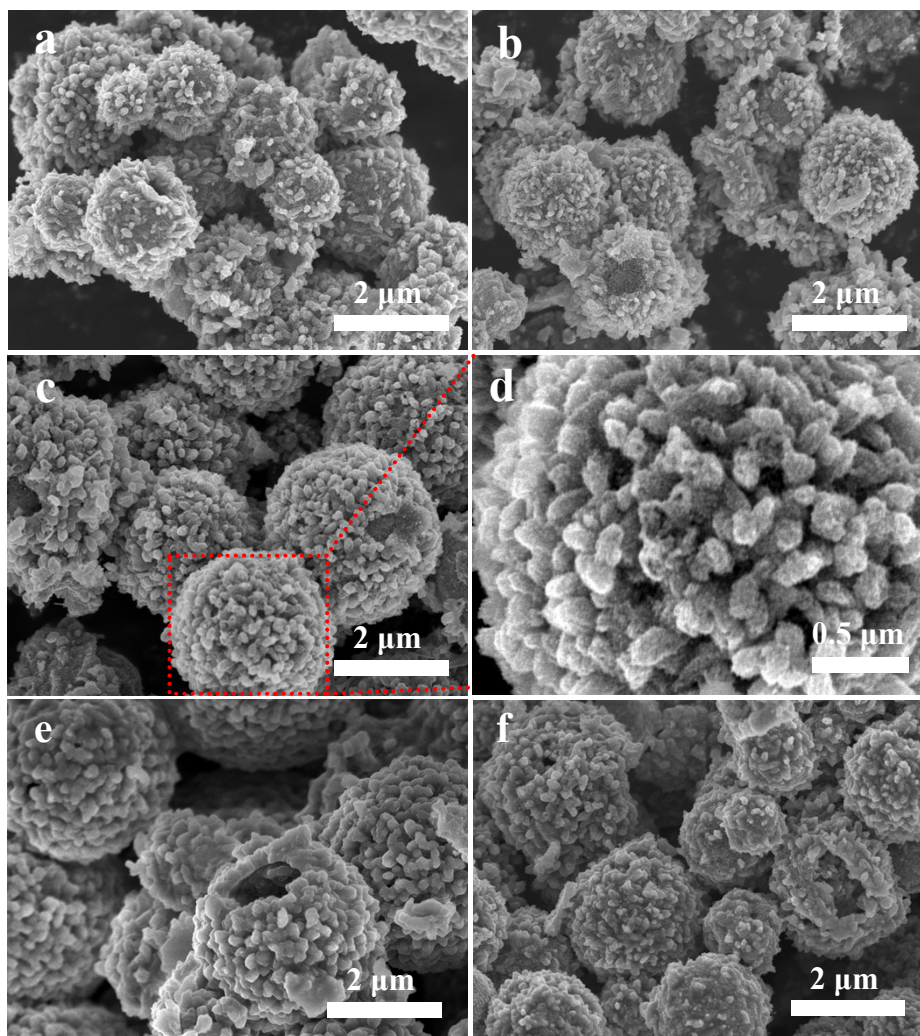


Figure S5 (a) SEM images of (a) YS Ni₂P/Ni@C/G, (b) YS Ni₉S₈/Ni@C/G, and (c-f) YS Ni₂P_{1-x}S_x/Ni@C/G, respectively.

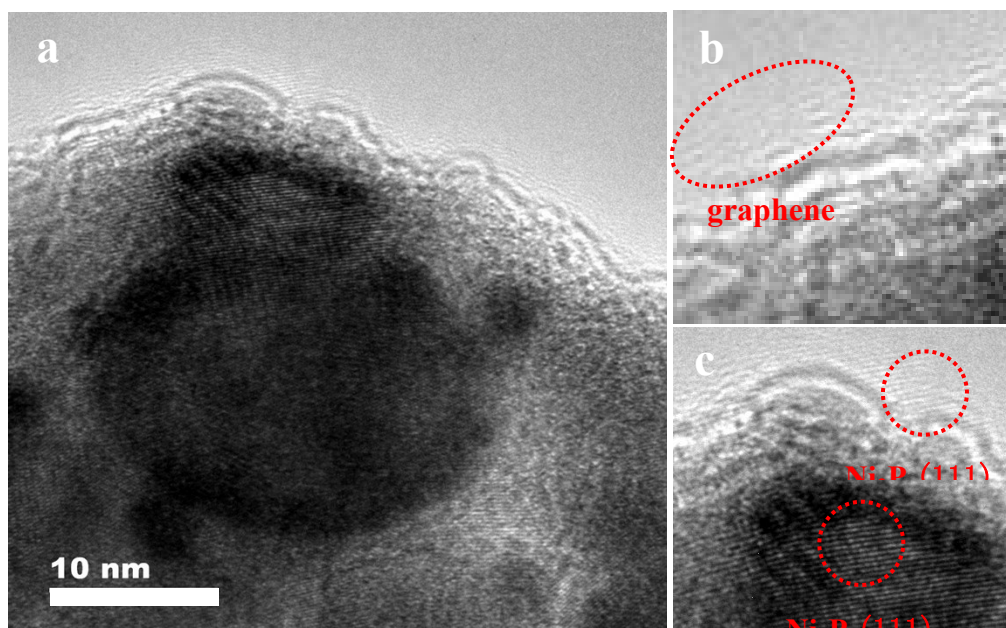


Figure S6 TEM images of YS $\text{Ni}_2\text{P}_{0.75}\text{S}_{0.25}/\text{Ni}@C/G$.

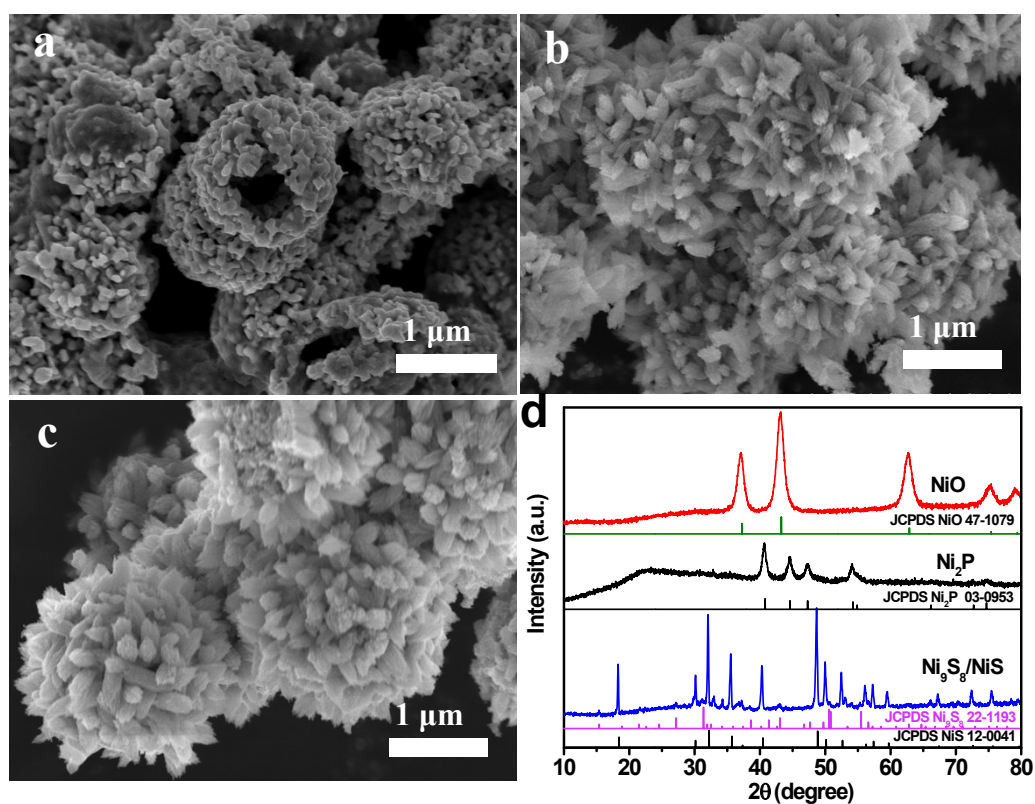


Figure S7 SEM images of porous (a) NiO , (b) Ni_2P , (c) $\text{Ni}_9\text{S}_8/\text{NiS}$, and (d) their corresponding XRD patterns, respectively.

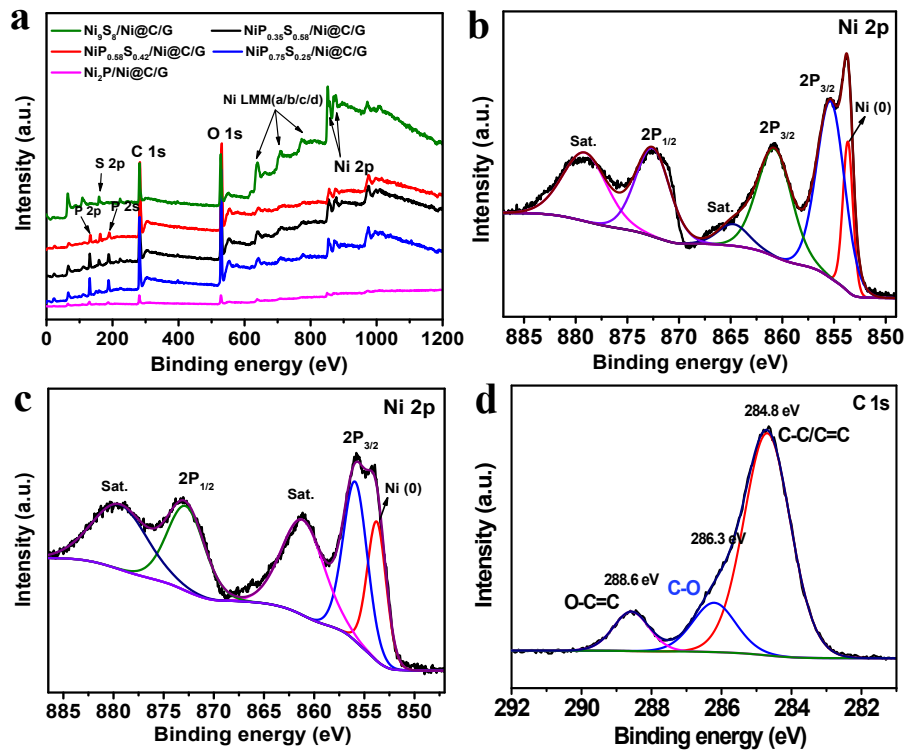


Figure S8 (a) XPS full survey spectra of YS $\text{NiP}_{1-x}\text{S}_x/\text{Ni}@C/\text{G}$, $\text{Ni}_2\text{P}/\text{Ni}@C/\text{G}$ and $\text{Ni}_9\text{S}_8/\text{Ni}@C/\text{G}$, (b) Ni 2p in YS $\text{Ni}_2\text{P}/\text{Ni}@C/\text{G}$, (c) Ni 2p in YS $\text{Ni}_9\text{S}_8/\text{Ni}@C/\text{G}$, (d) C 1s in YS $\text{Ni}_2\text{P}_{0.75}\text{S}_{0.25}/\text{Ni}@C/\text{G}$.

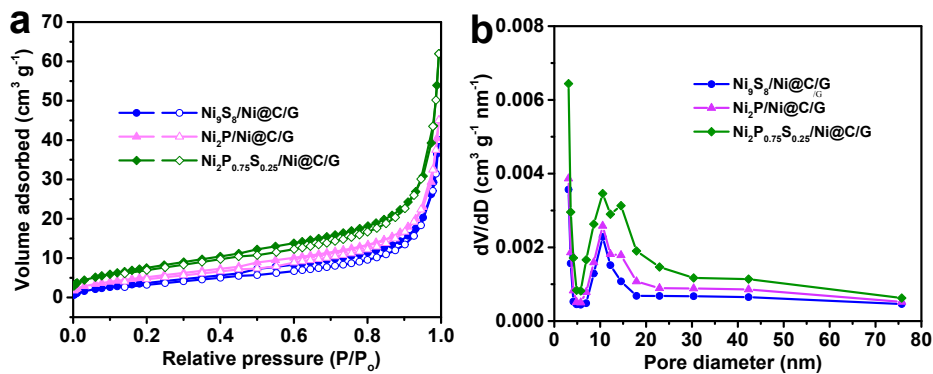


Figure S9 (a) N_2 adsorption-desorption isotherms and (b) pore-size distribution of YS $\text{Ni}_2\text{P}/\text{Ni}@C/\text{G}$, YS $\text{Ni}_9\text{S}_8/\text{Ni}@C/\text{G}$, and YS $\text{Ni}_2\text{P}_{0.75}\text{S}_{0.25}/\text{Ni}@C/\text{G}$, respectively.

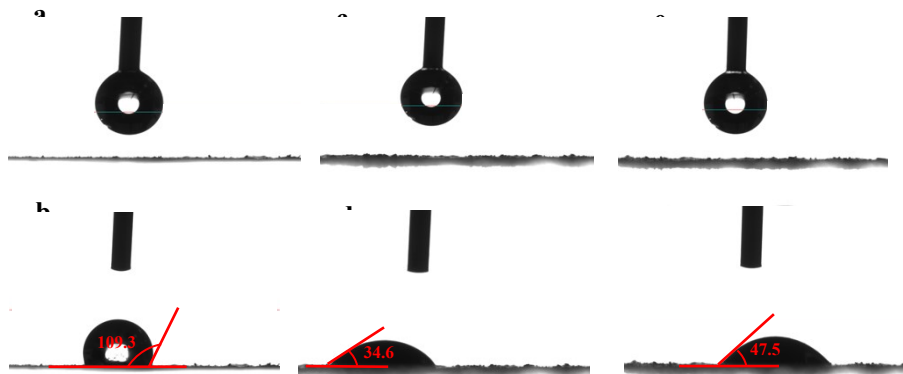


Figure S10 Surface wetting of H₂O droplet on (a, b) YS Ni₉S₈/Ni@C/G, (c, d) YS Ni₂P/Ni@C/G, and (d, f) YS Ni₂P_{0.75}S_{0.25}/Ni@C/G, respectively.

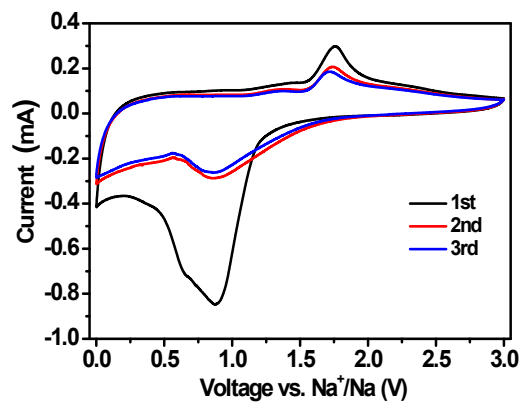


Figure S11 CV curves of YS Ni₂P_{0.75}S_{0.25}/Ni@C/G at a current density of 0.2 mV S⁻¹.

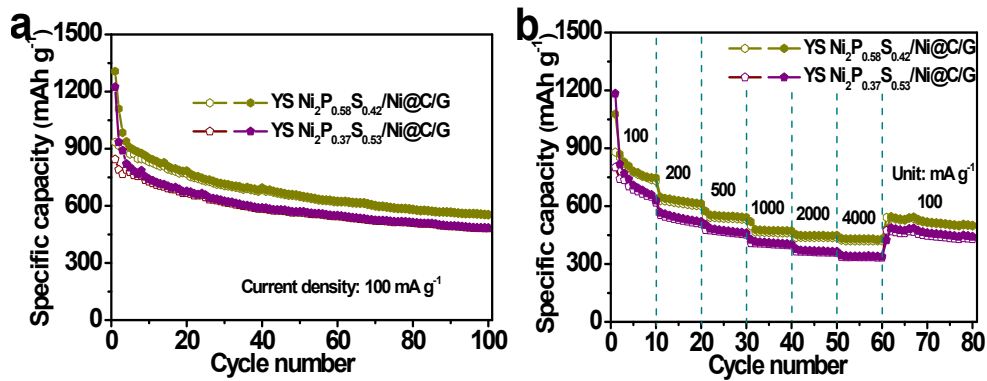


Figure S12 (a) Cycling stability at 100 mA g⁻¹ and (a) rate capabilities of YS Ni₂P_{0.58}S_{0.42}/Ni@C/G and YS Ni₂P_{0.37}S_{0.53}/Ni@C/G for SIBs, respectively.

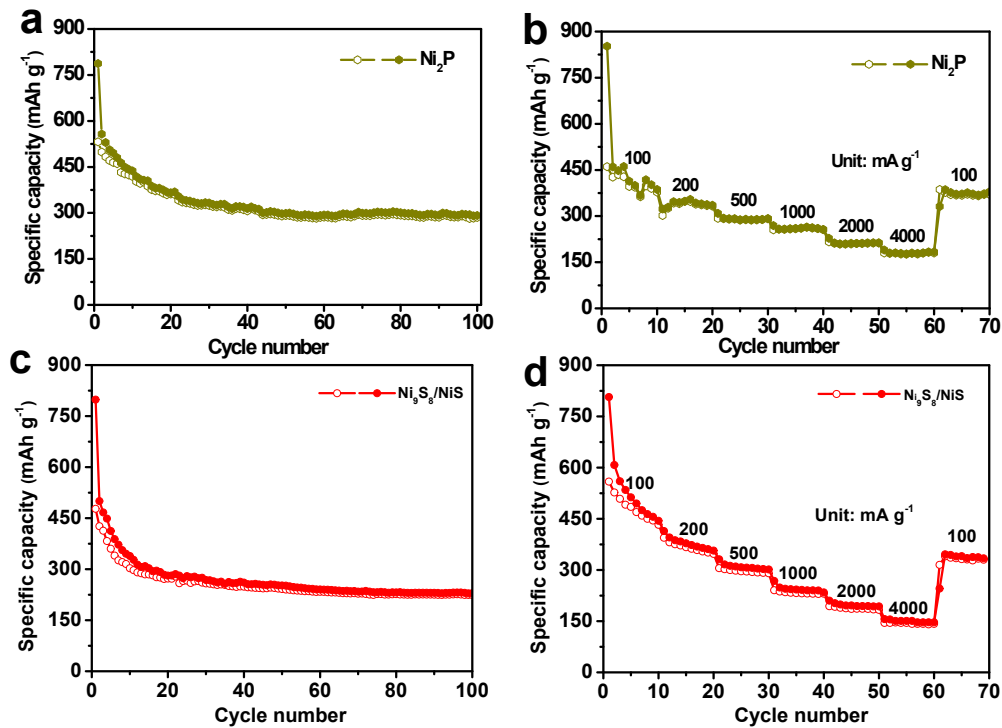


Figure S13 Cycling stability at 100 mA g⁻¹ and rate capabilities of (a, b) Ni₂P, and (c, d) Ni₉S₈/NiS for SIBs, respectively.

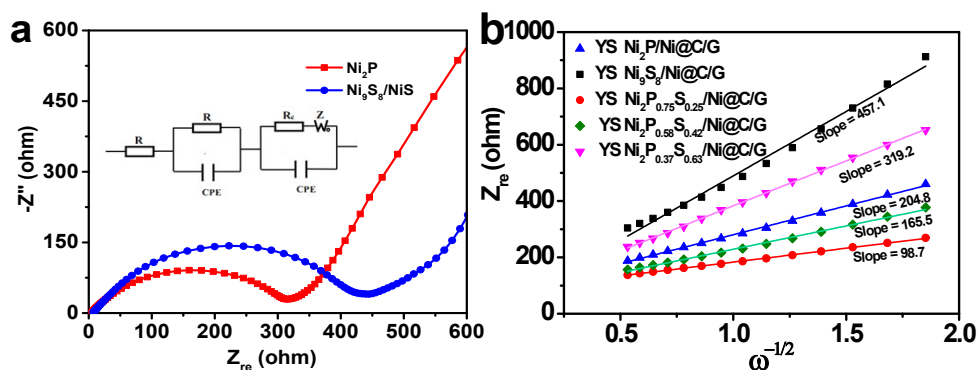


Figure S14 (a) Nyquist impedance plots of Ni₂P and Ni₉S₈/NiS after 100 cycles, and (b) the relationship plot between Z' and $\omega^{-1/2}$.

Table S2 Electrochemical impedance parameters of as-obtained Ni-based anodes for SIBs from equivalent circuit fitting of experimental data.

Sample	Cycle number	R_s /Ohm	R_f /Ohm	R_{ct} /Ohm
Ni ₉ S ₈ /NiS	100 th cycle	5.7	109.3	319.0
YS Ni ₉ S ₈ /Ni@C/G	100 th cycle	4.6	28.89	56.6
Ni ₂ P	100 th cycle	5.4	107.8	208.1
YS Ni ₂ P/Ni@C/G	100 th cycle	4.7	25.3	36.9
YS Ni ₂ P _{0.75} S _{0.25} /Ni@C/G	100 th cycle	4.7	24.9	36.0
YS Ni ₂ P _{0.58} S _{0.42} /Ni@C/G	100 th cycle	4.8	26.7	37.6
YS Ni ₂ P _{0.37} S _{0.63} /Ni@C/G	100 th cycle	4.6	26.4	38.3

Equations (1) and (2):

$$D = \frac{R^2 T^2}{2A^2 n^4 F^4 c^2 \sigma_w^2} \quad (1) \quad Z' = R' + \sigma_w \omega^{-1/2} \quad (2)$$

Where R is the gas constant, T is the absolute temperature, A is the surface area of the electrode, n is the number of transferred electrons per molecule, F is the Faraday constant, c is the molar concentration of Na⁺ ions, R' mainly involves the interface impedance and charge transfer resistances for these electrodes, ω ($\omega = 2\pi f$) is the angular frequency, and σ_w is the Warburg factor ($Z' \propto \sigma_w \omega^{-1/2}$), respectively.

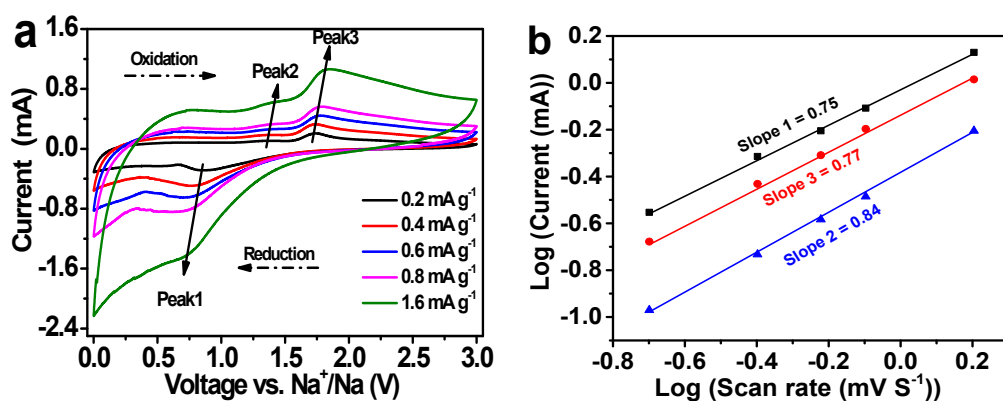


Figure S15 (a) CV scans of YS $\text{Ni}_2\text{P}_{0.75}\text{S}_{0.25}/\text{Ni}@C/\text{G}$ at various rates and (b) correspondingly fitted b-value at respective redox peaks for SIBs anode.

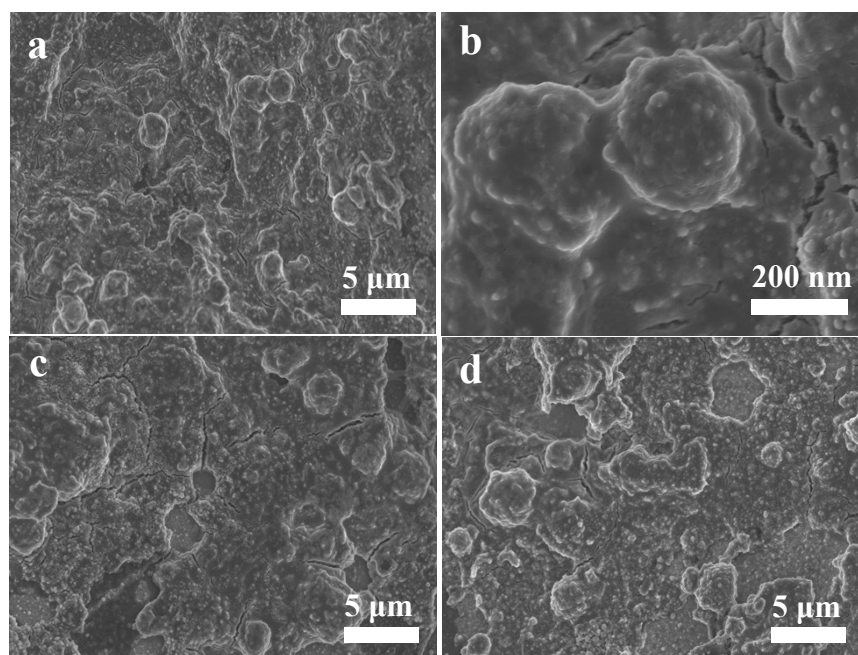


Figure S16 SEM images of (a, b) YS $\text{Ni}_2\text{P}_{0.75}\text{S}_{0.25}/\text{Ni}@C/\text{G}$, (c) YS $\text{Ni}_2\text{P}_{0.58}\text{S}_{0.42}/\text{Ni}@C/\text{G}$ and (d) YS $\text{Ni}_2\text{P}_{0.37}\text{S}_{0.53}/\text{Ni}@C/\text{G}$ after 100 cycles at 100 mA g^{-1} , respectively.

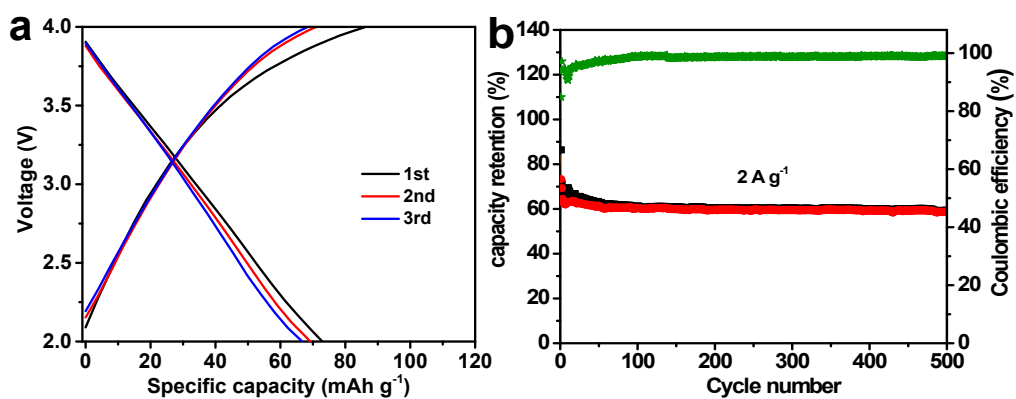


Figure S17 (a) GCD curves, and (b) cycle performance at 2 A g⁻¹ of the AC cathode for Na-storage.

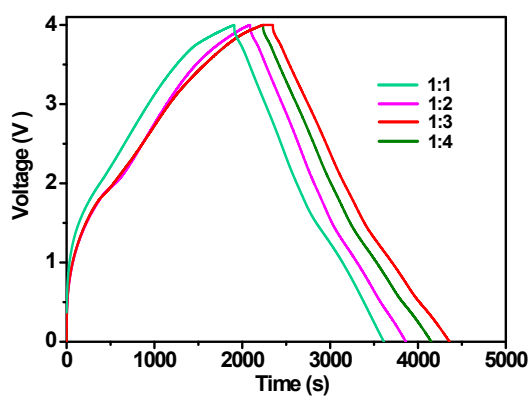


Figure S18 GDC curves of SICs with different mass ratios (anode: cathode, 1:1, 1:2, 1:3, and 1:4) at a current density of 0.5 A g⁻¹.

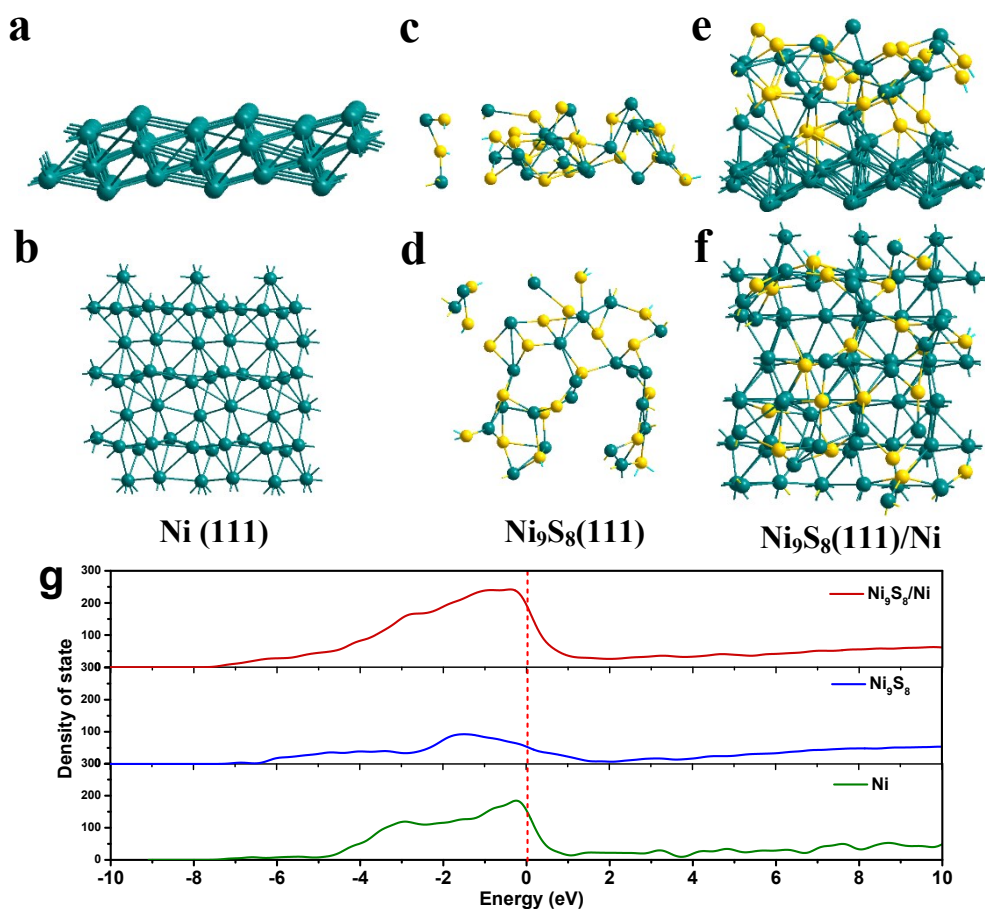


Figure S19 (a, c, e) Side-, and (b, d, f) top-views schematic model of the Ni (111), Ni_9S_8 (222), and the Ni_9S_8 (222)-Ni, and (g) DOS curves for Ni (111), Ni_9S_8 (222), and the Ni_9S_8 (222)/Ni.

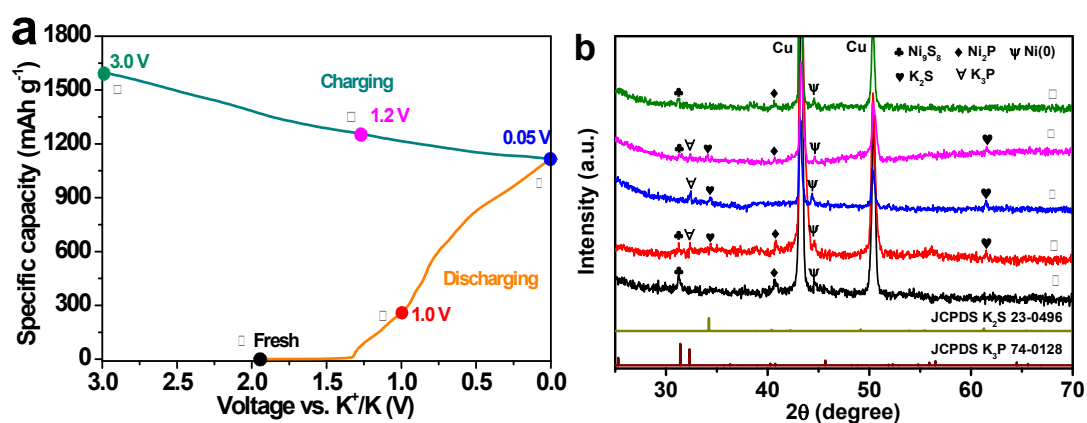


Figure S20 (a) The first charge-discharge profile and (b) its corresponding ex-situ XRD patterns of YS $\text{Ni}_2\text{P}_{0.75}\text{S}_{0.25}/\text{Ni}@C/\text{G}$ anode in PIBs at the different voltage platforms.

Table S3 Performance comparison of between $\text{Ni}_2\text{P}_{0.75}\text{S}_{0.25}/\text{Ni}@C/\text{G}$ and the reported anode materials for PIBs

Sample	Cycling performance (mAh g ⁻¹)/cycle number, current density (mA g ⁻¹)	Rate capability (mAh g ⁻¹)/current density (mA g ⁻¹)	Reference
$\text{Ni}_2\text{P}_{0.75}\text{S}_{0.25}/\text{Ni}@C/\text{G}$	372/200, 150	238/3200	This work
NiS ₂ @C@C	303/100, 50	151/1610	<i>Adv. Funct. Mater.</i> 2019, 29, 1903454
ZnSe-FeSe ₂ /RGO	363/100, 50	--	<i>J. Power Sources</i> 2020, 455, 227937
Y-S NiS _x @C	364/200, 100	232/2000	<i>J. Mater. Chem. A</i> , 2019, 7, 18932
mp-Co ₉ S ₈ @C/rGO	408/100, 200	278/2000	<i>Nano Res.</i> 2020, 13, 802-809
Fe-Ni-P hollow nanoframes	60/700, 200	46/2000	<i>Chem. Eng. J.</i> 2020, 390, 124515
FeS ₂ @G@CNF	205/100, 200	171/1000	<i>Small</i> 2019, 15, 1804740
Hollow V ₂ O ₃ @C sphere	330/500, 100	125/2000	<i>J. Mater. Chem. A</i> , 2020, 8, 13261
r-SnP@C	355/300, 100	258/1000	<i>Carbon</i> 2020, 168, 468-474
CoP@NPPCS	127/1000, 100	54/2000	<i>Adv. Mater.</i> 2018, 30, 1802310
TiO _x N _y /C	125/100, 200	72/1600	<i>Chem. Eng. J.</i> 2019, 369, 828-833
N/O Dual-dope hard Carbon-800	305/100, 100	223/2000	<i>Adv. Sci.</i> 2020, 7, 1902547
SnO ₂ @CF	399/150, 100	247/2000	<i>Energy Environ. Sci.</i> , 2020,13, 571-578
NC@CoP/NC	279/100, 100	200/2000	<i>Small</i> 2020, 16, 1906566

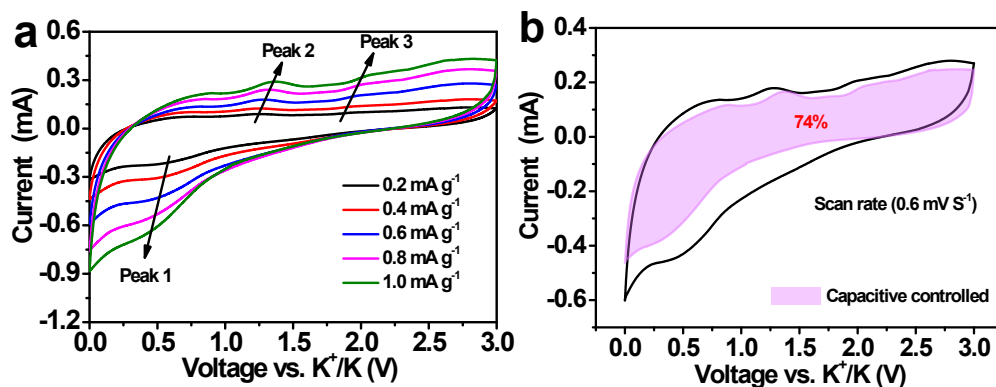


Figure S21 (a) CV scans of YS Ni₂P_{0.75}S_{0.25}/Ni@C/G at various rates, and (b) the shaded region shows the CV profile with the capacitive contribution at a scan rate of 0.6 mV s⁻¹ for PIBs anode.

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